

# Understanding Plating Stains

Charles S. Leech Jr.

**S**taining of precious metal plated surfaces has become a critical concern for electroplaters. We must implement drying processes other than CFC displacement. The CFC displacement method did not dry water from the plated surfaces. It simply floated the rinsewater from the surface. Now we must meet the challenge of drying water directly from the plated surface. While staining is a difficult problem, there are some viable solutions. Altos Engineering, Inc., was faced with this issue while developing a chemical-free drying process for several electroplating firms that provide 0.9999 gold-plated components to manufacturers of military and commercial semiconductors.

## The Nature of the Plating Stain

While it is very helpful to identify the contaminants that make up the visual defect, their identity is absolutely required to solve the staining problem. The bulk of the multicolor stains on gold plating are caused by potassium cyanide salts. Stains on other plated surfaces are most likely plating salts as well. It was routinely thought, however, that these salts were removed from the surfaces by the rinsing process. We have evidence that this is not always true. Previously, the salts were not deposited on the surface when the rinsewater was evaporated from the surface.

## How Plating Stains Are Formed

Typically, plating stains are seen as irregular-shaped "hollow" blemishes (Fig. 1). The most likely cause is a concentration of the staining salts during drying of rinse water.

Droplets form on wetted areas as the plated items are removed from the rinsewater. If the rinsewater contains dissolved plating salts and/or other water-soluble contaminants, staining is likely to occur. As the rinsewater dries

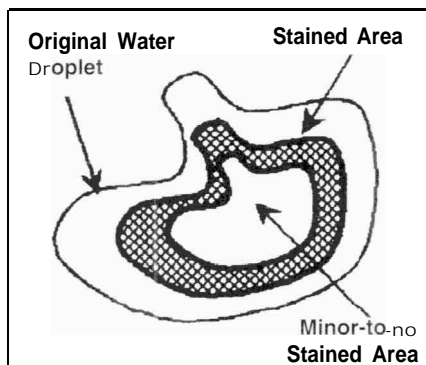


Fig. 1—Formation of a plating stain

from the surface, the volume of the original water droplet is reduced through evaporation.

As the volume of the droplet decreases, the concentration of contaminants becomes so great that the rinsewater can no longer hold all of it in suspension. At this point, contaminants drop out of the rinsewater and form the stained area. The salts from the rinsewater are deposited on the plated surface until no significant amount is present. Reduced staining is seen in the center area, which accounts for the "hollow" stain pattern.

## More Effective Post-Plating Processes Are Required

Three post-plating processes should be examined, with an eye to reducing or eliminating plating stains. The first is aqueous-based, between the plating bath and the rinse processes. The second is the plating rinse process, and the third consideration is the method of non-CFC drying. All these should be properly set up, or plating staining will continue.

## Cleaning and Rinsing Processes

Adding a simple, aqueous-based cleaning process can be extremely effective in capturing plating contaminants before they can be transferred to the final plating rinse bath. Testing has shown that most commercial aqueous clean-

ing solutions are not well suited for removing plating contaminants. The semiconductor industry has been instrumental in driving development of solutions that are highly effective in removing and capturing plating contaminants. Much of this work was done by Altos Engineering, Inc., as a working member of the JEDEC ad hoc "Marking Improvement Committee."

Wash and rinse bath temperatures are also very important to effectively rinse away plating residues. As a rule of thumb, rinsing becomes twice as effective as the temperature of a bath is increased by 10 °C. As illustrated in Fig.2, this is a very significant factor.

Agitation is another important factor that can improve the efficiency of post-plating washing and rinsing processes. As in the cleaning process, fresh material must be moved across the contaminated surface to remove water-soluble contaminants. The fluid at the interface of the plated surface and the washing and rinsing solutions will become saturated and ineffective very quickly. Fresh, unsaturated solutions must be brought to the contaminated surface on an almost-continuous basis. The agitation method used for effective plating is not always the most effective method for washing and rinsing away plating bath contaminants.

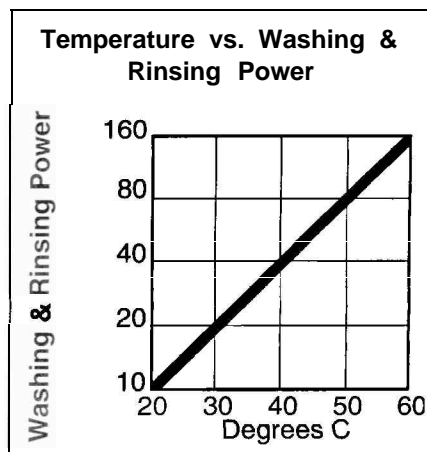


Fig. 2—Temperature vs. solution effectiveness.

### Rapid Surface Cooling Through Loss of Latent Energy Caused by Evaporation

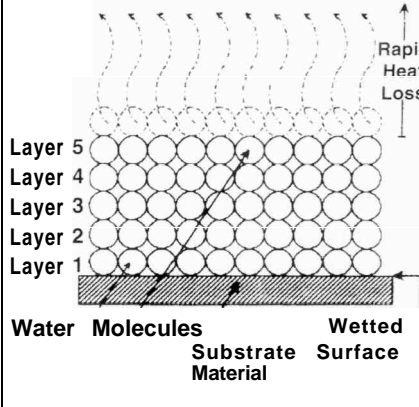


Fig. 3-The physics of vaporization of water.

### Rinsing Process Considerations

The first consideration should be the quality of the rinsewater. The water used by electroplates ranges from city-supplied drinking water through high-purity, deionized water. In between, there is distilled and reverse osmosis-treated water. We have found that deionized water is far more effective in removing plating salts and contaminants from plated surfaces. Deionized water, at a conductivity level of 18 megohms, is most effective in rendering plating salts soluble.

Rinsewater collects high levels of plating contaminants very rapidly. Plating baths that employ a reverse cascade are most effective in removing soluble salts. Frequent replacement of rinsewater is critical for effective rinsing.

### Drying Processes

There are a number of industry-accepted methods of removing water from plated surfaces. These include CFC and other water displacement techniques. Hot air knives, convection ovens, alcohol absorption, and centrifugal dryers are commonly used for rugged, non-critical plated objects. Recently, another non-CFC alternative drying process has been developed. It effectively removes rinsewater from such critical articles as those with blind holes, those in intimate contact with each other, those most likely to have plating stains or those which are delicate in nature. This is thermal/vacuum drying. It was developed for components used in semiconductor and other electronic devices. This is a patented technique that employs a vacuum to reduce the boiling point of the rinsewater. Moisture is rapidly evaporated from surfaces and cavities, blind holes and from surfaces in contact with one another. Rapid removal of rinsewater greatly reduces the inci-

dence of plating stains by removing the water and some salts before they can be deposited on the plated surface. As an example of the speed of thermal/vacuum drying, 3.2 pounds of water can be removed from 18 pounds of deep drawn, nickel-plated cans in approximately 10 min.

To better understand the fundamentals of drying of water, one must understand some simple physics that pertain to its vaporization. Water can best be thought of as multiple layers of molecules. Each layer is stacked on top of the lower layer. The uppermost layer must be removed before the underlying layers of molecules can be vaporized (Fig. 3).

Under reduced atmospheric pressure, the layers of water rapidly vaporize. With vaporization comes an almost instantaneous loss of temperature. **Each gram of water that is vaporized removes approximately 540 BTUs of energy from the upper layer of water.**

Water is a poor conductor of thermal energy. It has a thermal conductivity index of 1.6. (Compare this to 2024 aluminum, with an index of 480.) Vaporization under reduced atmospheric pressure occurs so rapidly that thermal conduction from the substrate is too slow to prevent a rapid drop in the temperature of the upper layers of water. As the rinsewater temperature is reduced, the vapor pressure of the water is dramatically reduced (Fig. 4). This impedes the rapid removal of moisture.

Without computer-controlled thermal energy to the uppermost surface of the moisture, the vapor pressure of the water will be driven dramatically downward (Fig. 4). The thermal/vacuum drying process applies make-up energy to prevent the drop in vapor pressure.

Thermal/vacuum drying is effective in removing water from a blind hole, because it reduces the water to a gas (water

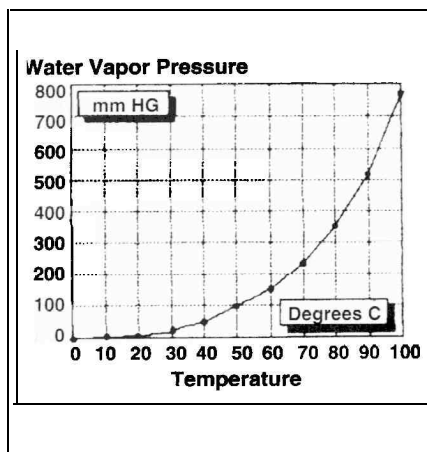


Fig. 4-Vapor pressure of water vs. temperature.

### Water Trapped in Blind Hole By Surface Tension and Air Pressure

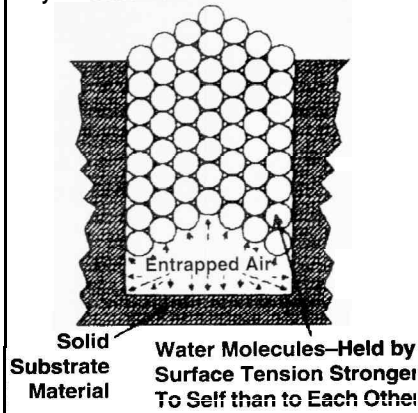


Fig. 5-Expelling water from a blind hole.

vapor) which can be almost instantly removed from the drying chamber. This transformation of water into a gas is very effective when dealing with water in crevices and blind holes. **The holes are filled with water, but are not usually full of water.** Small amounts of air are trapped with the water. When atmospheric pressure is reduced, this entrapped air expands explosively, blowing the water out of the holes. The same reaction is seen when two wet surfaces are in contact with one another.

The time allotted for drying is usually an arbitrary period. The thermal/vacuum system automatically compensates for varying volumes of water to be removed. The system monitors the creation of water vapor, vs. the vacuum level produced by the pump. When a preset level of vacuum is attained, water cannot be present in the process chamber.

### About the Author

**Charles S. Leech, Jr.** is a graduate of Arizona State University. He has served on the advanced engineering staffs of such firms as Honeywell, Inc., United Technologies, Inc., Texas Instruments, Inc., and Motorola SPD, Inc. As a senior engineer, Leech is involved in the fields of new equipment and process development. He is Director of Engineering for Altos Engineering, Inc. of Glendale, 6009 N. 61st Ave., AZ 85301, where cleaning and drying systems for various industries are developed. He is a speaker for both the Microelectronics Packaging and Processing Engineers and SEMI associations. Leech is named on five United States Patents.

This is the first of two articles on plating stains. Next month Leach discusses eliminating them.